TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7SA32F,TC7SA32FU

2-Input OR Gate

Features

Low voltage operation: V_{CC} = 1.8~3.6 V

• High speed operation : t_{pd} = 2.8 ns (max) (V_{CC} = 3.0~3.6 V)

: t_{pd} = 3.7 ns (max) (V_{CC} = 2.3~2.7 V)

: t_{pd} = 7.4 ns (max) (V_{CC} = 1.8 V)

• High Output current : I_{OH}/I_{OL} = ±24 mA (min) (V_{CC} = 3.0 V)

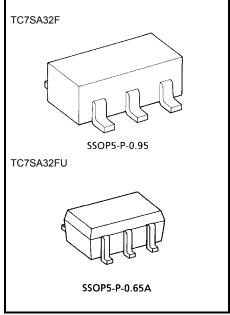
: I_{OH}/I_{OL} = ±18 mA (min) (V_{CC} = 2.3 V)

: $I_{OH}/I_{OL} = \pm 6 \text{ mA (min) (V}_{CC} = 1.8 \text{ V)}$

3.6-V tolerant inputs

• 3.6-V power down protection output

• TC74VCX32 equivalent



Weight

SSOP5-P-0.95 : 0.016 g (typ.) SSOP5-P-0.65A : 0.006 g (typ.)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit	
Power supply voltage	V _{CC}	-0.5~4.6	V	
DC input voltage	V _{IN}	-0.5~4.6	V	
DC output voltage	V	-0.5~4.6 (Note 1)	V	
DC output voltage	V _{OUT}	-0.5~V _{CC} + 0.5 (Note 2)	V	
Input diode current	I _{IK}	-50	mA	
Output diode current	lok	-50 (Note 3)	mA	
DC output current	lout	±50	mA	
Power dissipation	PD	200	mW	
DC V _{CC} /ground current	Icc	±100	mA	
Storage temperature range	T _{stg}	-65~150	°C	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

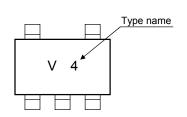
Note 1: $V_{CC} = 0 V$

Note 2: High or low state. IOUT absolute maximum rating must be observed.

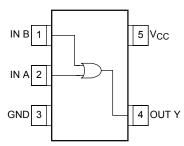
Note 3: Vout < GND

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Marking



Pin Assignment (top view)



Logic Diagram



Truth Table

Inputs		Output
Α	В	Υ
L	L	L
L	Н	Н
Н	L	Н
Н	Н	Н

Operating Ranges

Characteristics	Symbol	Rating	Unit	
Dower cumply voltage	V	1.8~3.6	٧	
Power supply voltage	V _{CC}	1.2~3.6 (Note 4)		
Input voltage	V _{IN}	-0.3~3.6	V	
Output voltage	Vout	0~3.6 (Note 5)	V	
Output voltage	VOU1	0~V _{CC} (Note 6)	V	
		±24 (Note 7)		
Output current	I _{OH} /I _{OL}	±18 (Note 8)	mA	
		±6 (Note 9)		
Operating temperature range	T _{opr}	-40~85	°C	
Input rise and fall time	dt/dv	0~10 (Note 10)	ns/V	

Note 4: Data retention only

Note 5: $V_{CC} = 0 V$

Note 6: High or low state

Note 7: $V_{CC} = 3.0 \sim 3.6 \text{ V}$

Note 8: $V_{CC} = 2.3 \sim 2.7 \text{ V}$

Note 9: $V_{CC} = 1.8 \text{ V}$

Note 10: $V_{IN} = 0.8 \sim 2.0 \text{ V}, V_{CC} = 3.0 \text{ V}$

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Electrical Characteristics

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DC Characteristics (Ta = $-40\sim85^{\circ}$ C, 2.7 V < V_{CC} \leq 3.6 V)

Characteristics		Symbol Test Co		Condition		Min	Max	Unit
		Cymbol	10010	root condition			Wax	Onic
Input voltage	High level	V _{IH}		_	2.7~3.6	2.0	_	V
Input voltage	Low level	V _{IL}			2.7~3.6	_	0.8	V
				$I_{OH} = -100 \mu A$	2.7~3.6	V _{CC} - 0.2	_	
	High level	V _{OH}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	$I_{OH} = -12 \text{ mA}$	2.7	2.2	_	V
				$I_{OH} = -18 \text{ mA}$	3.0	2.4	_	
Output voltage				$I_{OH} = -24 \text{ mA}$	3.0	2.2	_	
		V _{OL}	$V_{IN} = V_{IL}$	I _{OL} = 100 μA	2.7~3.6	_	0.2	
	Low level			I _{OL} = 12 mA	2.7	_	0.4	
	Low level			I _{OL} = 18 mA	3.0	_	0.4	
				I _{OL} = 24 mA	3.0	_	0.55	
Input leakage curre	ent	I _{IN}	V _{IN} = 0~3.6 V		2.7~3.6	_	±5.0	μА
Power off leakage current		I _{OFF}	V _{IN} , V _{OUT} = 0~3.	V _{IN} , V _{OUT} = 0~3.6 V		_	10.0	μА
Quiescent supply current		Icc -	V _{IN} = V _{CC} or GND		2.7~3.6	_	20.0	
			$V_{CC} \le (V_{IN}, V_{OUT}) \le 3.6 \text{ V}$		2.7~3.6	_	±20.0	μΑ
Increase in I _{CC} pe	r input	Δlcc	$V_{IH} = V_{CC} - 0.6 V$	/	2.7~3.6		750	

DC Characteristics (Ta = -40~85°C, 2.3 V \leq V_{CC} \leq 2.7 V)

Characteristics		Symbol	Symbol Test Condition			Min	Max	Unit
	, i			V _{CC} (V)				
Input voltage	High level	V_{IH}	-	_	2.3~2.7	1.6	_	V
input voltage	Low level	V _{IL}	-	_	2.3~2.7		0.7	
				$I_{OH} = -100 \mu A$	2.3~2.7	V _{CC} - 0.2		
	High level	V _{OH}	VIN - VIH OI VIL	$I_{OH} = -6 \text{ mA}$	2.3	2.0	_	· v
Output voltage				I _{OH} = -12 mA	2.3	1.8	_	
				I _{OH} = -18 mA	2.3	1.7	_	
					$I_{OL} = 100 \mu A$	2.3~2.7	_	0.2
	Low level	V _{OL}	$V_{IN}=V_{IL} \\$	I _{OL} = 12 mA	2.3	_	0.4	•
				I _{OL} = 18 mA	2.3		0.6	
Input leakage curre	ent	I _{IN}	V _{IN} = 0~3.6 V		2.3~2.7	_	±5.0	μА
Power off leakage	current	IOFF	V _{IN} , V _{OUT} = 0~3.	6 V	0	_	10.0	μА
Outpoont ourselve	Quiescent supply current		V _{IN} = V _{CC} or GND		2.3~2.7	_	20.0	μА
Quiescent supply (V _{CC} ≤ (V _{IN} , V _{OUT}	$V_{CC} \le (V_{IN}, V_{OUT}) \le 3.6 \text{ V}$		_	±20.0	



DC Characteristics (Ta = -40~85°C, 1.8 V \leq V_{CC} < 2.3 V)

Characteristics		Symbol Test Condition		condition		Min	Max	Unit
		Symbol	rest condition		V _{CC} (V)	IVIIII		Offic
Input voltage	High level	V _{IH}	-	_		0.7 × V _{CC}	ı	V
input voltage	Low level	V _{IL}	V _{IL} —		1.8~2.3	ı	0.2 × V _{CC}	٧
		V _{OH}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OH} = -100 \mu A$	1.8	V _{CC} - 0.2		
Output voltage				$I_{OH} = -6 \text{ mA}$	1.8	1.4		V
	Low level	V _{OL}	$V_{IN} = V_{IL}$	$I_{OL} = 100 \ \mu A$	1.8	_	0.2	
	Low level	VOL		I _{OL} = 6 mA	1.8	_	0.3	
Input leakage curre	ent	I _{IN}	V _{IN} = 0~3.6 V		1.8	_	±5.0	μА
Power off leakage current		l _{OFF}	V _{IN} , V _{OUT} = 0~3.6 V		0		10.0	μΑ
Quiescent supply current			V _{IN} = V _{CC} or GND		1.8	_	20.0	
		Icc	$V_{CC} \le (V_{IN}, V_{OUT}) \le 3.6 \text{ V}$		1.8	_	±20.0	μΑ

AC Characteristics (Ta = -40~85°C, input: $t_r = t_f = 2.0$ ns, $C_L = 30$ pF, $R_L = 500~\Omega$)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Min	Max	Unit
Propagation delay time	+		1.8	1.5	7.4	
		Figure 1, Figure 2	2.5 ± 0.2	1.0	3.7	ns
	^t pHL		3.3 ± 0.3	8.0	2.8	

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For $C_L = 50\ pF$, add approximately 300 ps to the AC maximum specification.



Dynamic Switching Characteristics (Ta = 25°C, input: $t_r = t_f = 2.0$ ns, $C_L = 30$ pF)

Characteristics	Symbol	Test Condition			Tura	Unit
Characteristics	Symbol	/mbol Test Condition		V _{CC} (V)	Тур.	Offic
		$V_{IN} = 1.8 \text{ V}, V_{IL} = 0 \text{ V}$ (No	te 11)	1.8	0.25	
Quiet output maximum dynamic V_{OL}	V_{OLP}	$V_{IN} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$ (No	te 11)	2.5	0.6	ns
		$V_{IN} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$ (No	te 11)	3.3	8.0	
		$V_{IN} = 1.8 \text{ V}, V_{IL} = 0 \text{ V}$ (No	te 11)	1.8	-0.25	
Quiet output minimum dynamic V _{OL}	V_{OLV}	$V_{IN} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$ (No	te 11)	2.5	-0.6	ns
		$V_{IN} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$ (No	te 11)	3.3	-0.8	
		$V_{IN} = 1.8 \text{ V}, V_{IL} = 0 \text{ V}$ (No	te 11)	1.8	1.5	
Quiet output minimum dynamic V _{OH}	V_{OHV}	$V_{IN} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$ (No	te 11)	2.5	1.9	ns
		$V_{IN} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$ (No	te 11)	3.3	2.2	

Note 11: Parameter guaranteed by design.

Capacitive Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition		Vcc (V)	Тур.	Unit
Input capacitance	C _{IN}	_		1.8, 2.5, 3.3	6	pF
Power dissipation capacitance	C _{PD}	f _{IN} = 10 MHz	(Note 12)	1.8, 2.5, 3.3	20	pF

Note 12: CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation.

 $I_{CC (opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

AC Test Circuit

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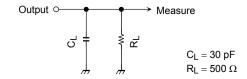
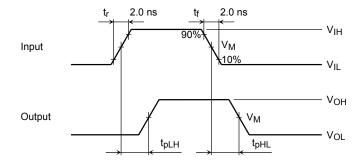


Figure 1

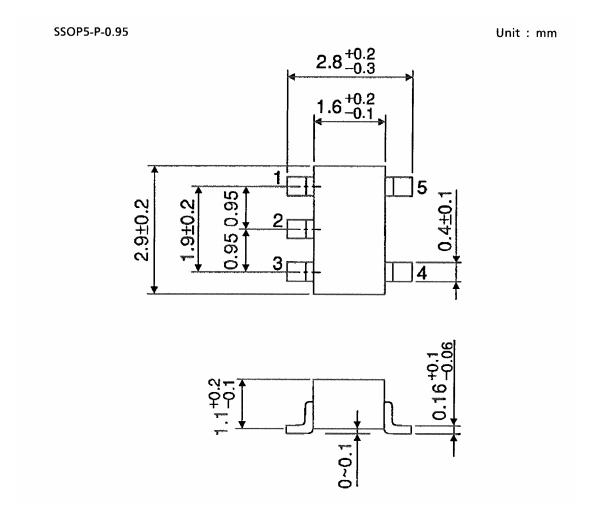
AC Waveforms



Symbol	V _{CC}							
Symbol	$3.3\pm0.3~\textrm{V}$	$2.5\pm0.2\textrm{V}$	1.8 V					
V _{IH}	2.7 V	V _{CC}	V _{CC}					
V _M	1.5 V	V _{CC} /2	V _{CC} /2					

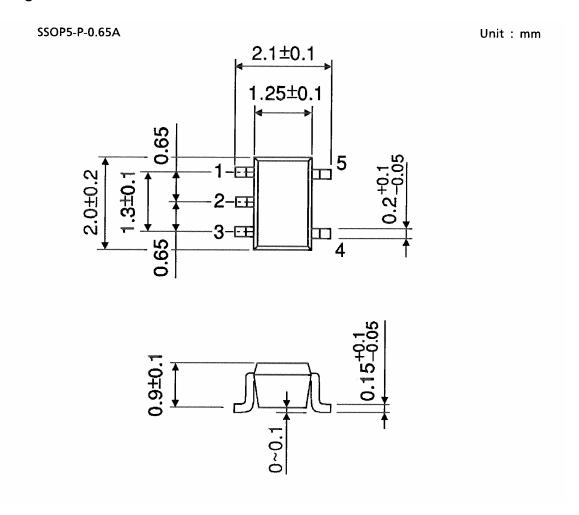
Figure 2 t_{pLH}, t_{pHL}

Package Dimensions



Weight: 0.016 g (typ.)

Package Dimensions



Weight: 0.006 g (typ.)

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